

MITSUBISHI IGBT MODULES
CM100DY-24NF

HIGH POWER SWITCHING USE

CM100DY-24NF



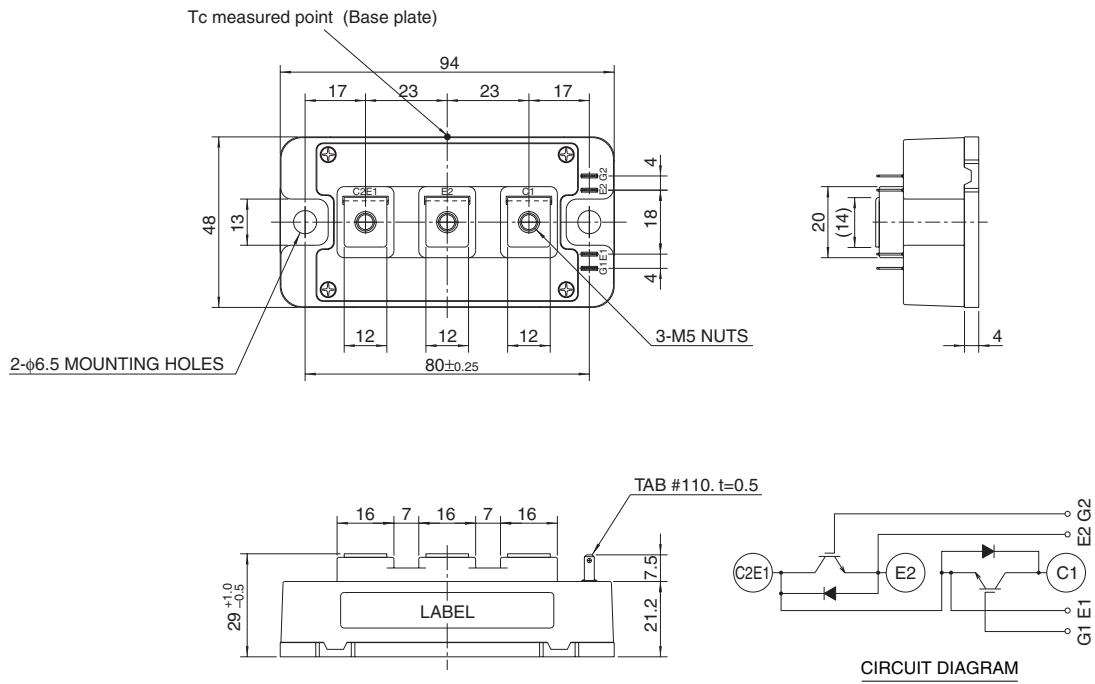
- IC 100A
- VCES 1200V
- Insulated Type
- 2-elements in a pack

APPLICATION

General purpose inverters & Servo controls, etc

OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm



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MAXIMUM RATINGS (T_j = 25°C, unless otherwise specified)

Symbol	Parameter	Conditions	Ratings	Unit
V _{CE} S	Collector-emitter voltage	G-E Short	1200	V
V _{GE} S	Gate-emitter voltage	C-E Short	±20	V
I _C	Collector current	DC, T _c ' = 113°C ^{*3}	100	A
I _{CM}		Pulse (Note 2)	200	A
I _E (Note 1)	Emitter current		100	A
I _{EM} (Note 1)		Pulse (Note 2)	200	A
P _C (Note 3)	Maximum collector dissipation	T _c = 25°C	650	W
T _j	Junction temperature		-40 ~ +150	°C
T _{stg}	Storage temperature		-40 ~ +125	°C
V _{iso}	Isolation voltage	Terminals to base plate, f = 60Hz, AC 1 minute	2500	V _{rms}
—	Torque strength	Main terminals M5 screw	2.5 ~ 3.5	N • m
—		Mounting M6 screw	3.5 ~ 4.5	N • m
—	Weight	Typical value	310	g

ELECTRICAL CHARACTERISTICS (T_j = 25°C, unless otherwise specified)

Symbol	Parameter	Test conditions	Limits			Unit	
			Min.	Typ.	Max.		
I _{CES}	Collector cutoff current	V _{CE} = V _{CE} S, V _{GE} = 0V	—	—	1	mA	
V _{GE(th)}	Gate-emitter threshold voltage	I _C = 10mA, V _{CE} = 10V	6	7	8	V	
I _{GES}	Gate leakage current	±V _{GE} = V _{GES} , V _{CE} = 0V	—	—	0.5	μA	
V _{CE(sat)}	Collector-emitter saturation voltage	I _C = 100A, V _{GE} = 15V	T _j = 25°C	—	1.8	2.5	V
			T _j = 125°C	—	2.0	—	
C _{ies}	Input capacitance	V _{CE} = 10V V _{GE} = 0V	—	—	23	nF	
C _{oes}	Output capacitance		—	—	2	nF	
C _{res}	Reverse transfer capacitance		—	—	0.45	nF	
Q _G	Total gate charge	V _{CC} = 600V, I _C = 100A, V _{GE} = 15V	—	675	—	nC	
t _{d(on)}	Turn-on delay time	V _{CC} = 600V, I _C = 100A V _{GE} = ±15V R _G = 3.1Ω, Inductive load I _E = 100A	—	—	120	ns	
t _r	Turn-on rise time		—	—	80	ns	
t _{d(off)}	Turn-off delay time		—	—	450	ns	
t _f	Turn-off fall time		—	—	350	ns	
t _{rr} (Note 1)	Reverse recovery time		—	—	150	ns	
Q _{rr} (Note 1)	Reverse recovery charge		—	5.0	—	μC	
V _{EC} (Note 1)	Emitter-collector voltage	I _E = 100A, V _{GE} = 0V	—	—	3.2	V	
R _{th(j-c)Q}	Thermal resistance ^{*1}	IGBT part (1/2 module)	—	—	0.19	K/W	
R _{th(j-c)R}		FWDi part (1/2 module)	—	—	0.35	K/W	
R _{th(c-f)}	Contact thermal resistance	Case to heat sink, Thermal compound Applied ^{*2} (1/2 module)	—	0.07	—	K/W	
R _{th(j-c')Q}	Thermal resistance	Case temperature measured point is just under the chips	—	—	0.13 ^{*3}	K/W	
R _G	External gate resistance		3.1	—	31	Ω	

*1 : Case temperature (T_c) measured point is shown in page OUTLINE DRAWING.

*2 : Typical value is measured by using thermally conductive grease of λ = 0.9[W/(m • K)].

*3 : Case temperature (T_c) measured point is just under the chips.

If you use this value, R_{th(f-a)} should be measured just under the chips.

Note 1. I_E, V_{EC}, t_{rr} & Q_{rr} represent characteristics of the anti-parallel, emitter-collector free-wheel diode (FWDi).

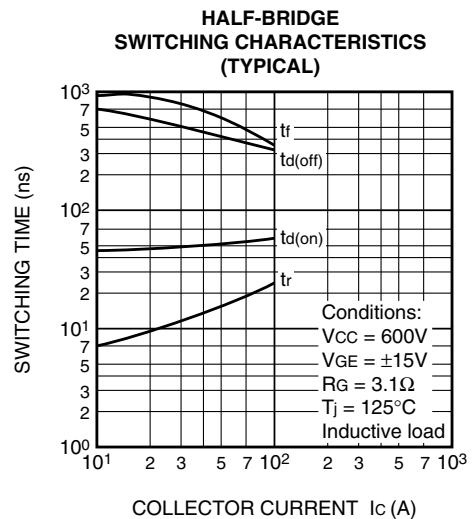
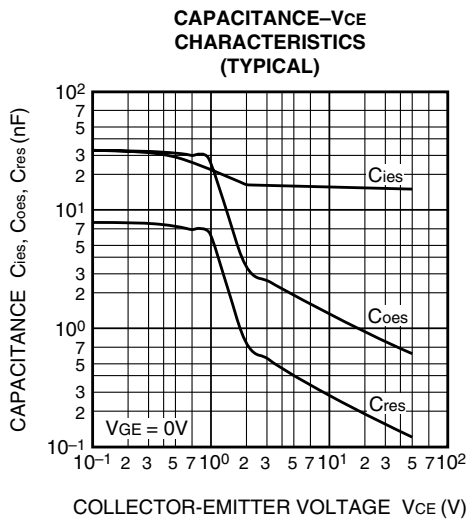
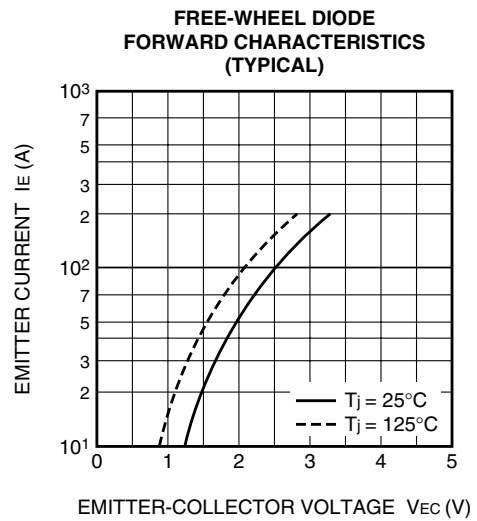
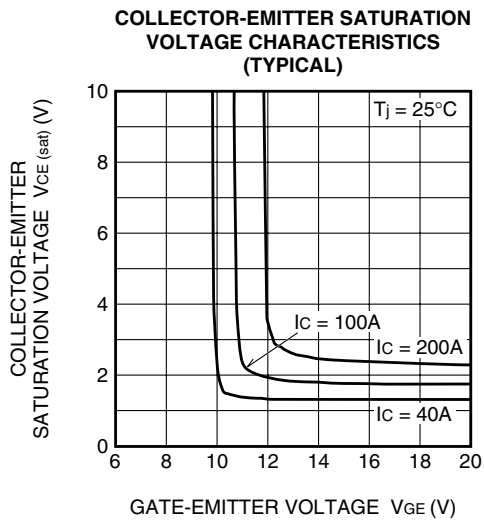
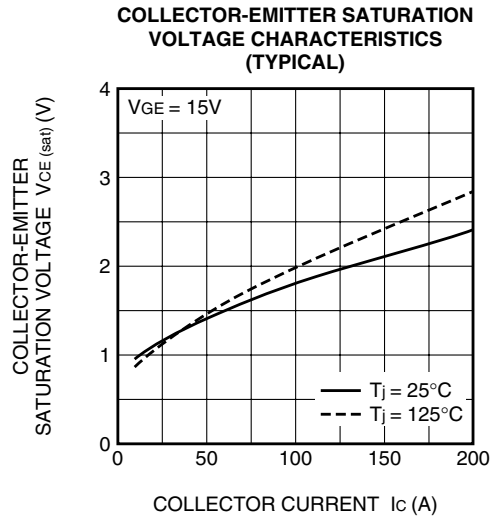
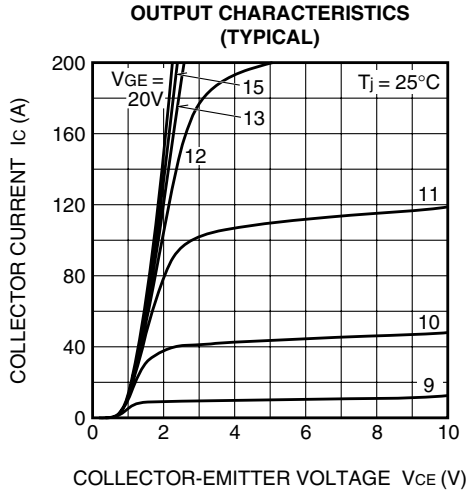
2. Pulse width and repetition rate should be such that the device junction temperature (T_j) does not exceed T_{jmax} rating.

3. Junction temperature (T_j) should not increase beyond 150°C.

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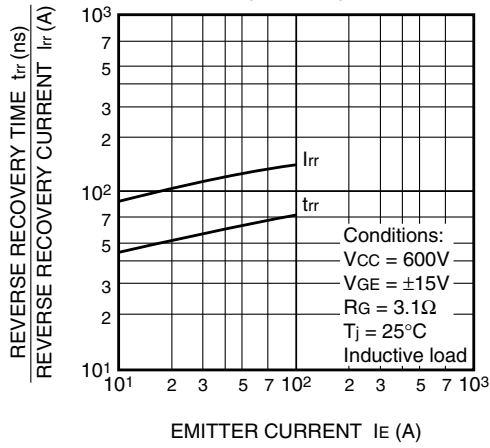
PERFORMANCE CURVES



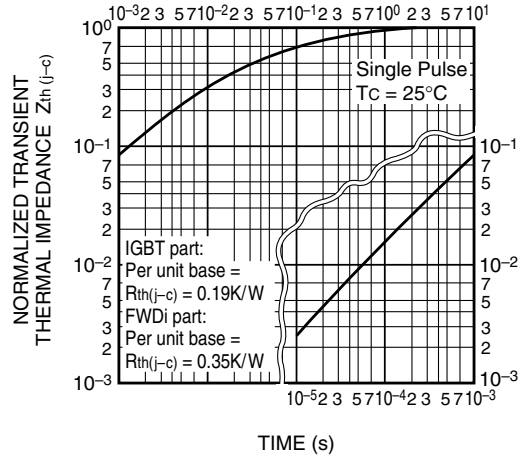
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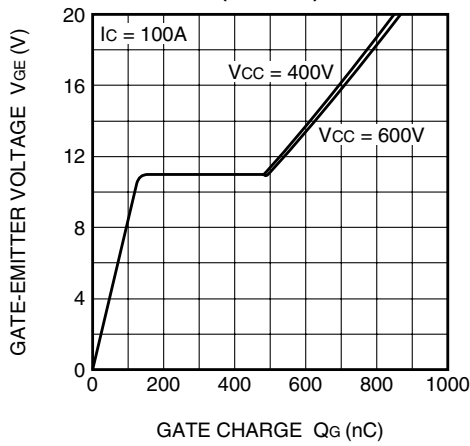
REVERSE RECOVERY CHARACTERISTICS OF FREE-WHEEL DIODE (TYPICAL)



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (IGBT part & FWDi part)



GATE CHARGE CHARACTERISTICS (TYPICAL)



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